

BAT54WS-HAF

Schottky Barrier Diode

Features

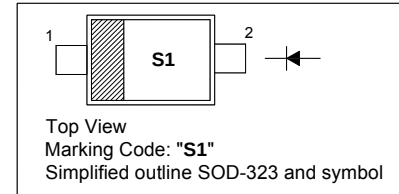
- Low forward voltage
- Guard ring protected
- Small plastic SMD SOD-323 package
- Halogen and Antimony Free(HAF), RoHS compliant

Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	30	V
Forward Current	I_F	200	mA
Repetitive Peak Forward Current	I_{FRM}	300	mA
Peak Forward Surge Current ($t_p = 10\text{ ms}$)	I_{FSM}	600	mA
Power Dissipation	P_{tot}	230	mW
Thermal Resistance from Junction Ambient	$R_{\theta JA}$	500	K/W
Junction Temperature	T_j	125	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^{\circ}\text{C}$

Characteristics at $T_a = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 0.1\text{ mA}$ at $I_F = 1\text{ mA}$ at $I_F = 10\text{ mA}$ at $I_F = 30\text{ mA}$ at $I_F = 100\text{ mA}$	V_F	240 320 400 500 800	mV
Reverse Current at $V_R = 25\text{ V}$	I_R	2	μA
Total Capacitance at $V_R = 1\text{ V}$, $f = 1\text{ MHz}$	C_{tot}	10	pF
Reverse Recovery Time at $I_F = 10\text{ mA}$, $V_R = 6\text{ V}$, $I_R = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{rr}	6	ns

TOP DYNAMIC

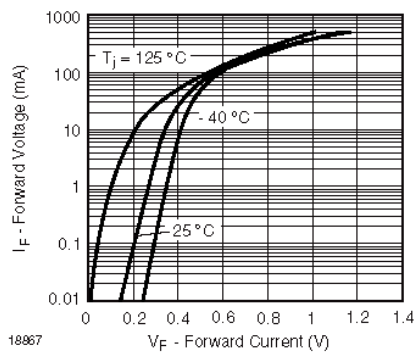


Figure 1. Typical Forward Voltage Forward Current at Various Temperatures

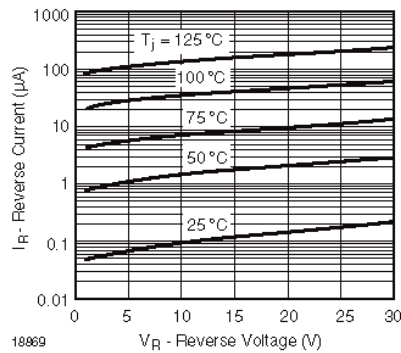


Figure 3. Typical Variation of Reverse Current at Various Temperatures

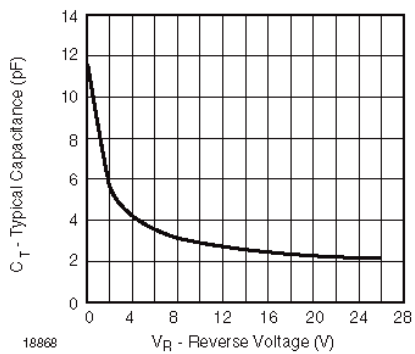


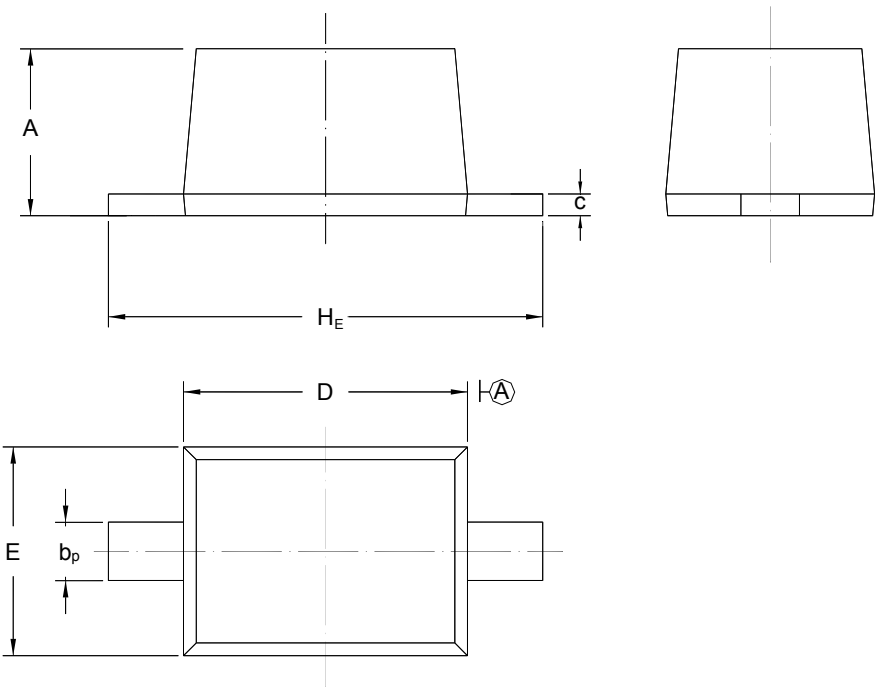
Figure 2. Typical Capacitance C_T vs. Reverse Applied Voltage V_R

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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b _p	C	D	E	H _E
mm	1.10 0.80	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30

TOP DYNAMIC